HALOGEN

FREE



Vishay General Semiconductor

Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | |
|-------------------------|----------------|--|--|
| I _{F(AV)} | 4.0 A | | |
| V_{RRM} | 100 V | | |
| I _{FSM} | 80 A | | |
| E _{AS} | 50 mJ | | |
| V_F at $I_F = 4.0 A$ | 0.61 V | | |
| T _J max. | 150 °C | | |
| Package | SMB (DO-214AA) | | |
| Circuit configuration | Single | | |

FEATURES

- Low profile package
- · Ideal for automated placement
- Trench MOS Schottky technology
- · Low power losses, high efficiency
- · Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** color band denotes the cathode end

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | |
|---|-----------------------------------|-------------|------|--|
| PARAMETER | SYMBOL | VSSB410S | UNIT | |
| Device marking code | | V4B | | |
| Maximum repetitive peak reverse voltage | V_{RRM} | 100 | V | |
| Maximum DC forward current | I _F ⁽¹⁾ | 4.0 | | |
| | I _F ⁽²⁾ | 1.9 | _ A | |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load | I _{FSM} 80 | | А | |
| Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH | E _{AS} | 50 | mJ | |
| Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C | I _{RRM} | 1.0 | А | |
| Operating junction and storage temperature range | T _J , T _{STG} | -40 to +150 | °C | |

Notes

⁽¹⁾ Mounted on 14 mm x 14 mm pad areas, 1 oz. FR4 P.C.B.

⁽²⁾ Free air, mounted on recommended copper pad area



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|-------------------------|-------------------------|-------------------------------|---------------|------|------|
| PARAMETER | TEST CO | TEST CONDITIONS | | TYP. | MAX. | UNIT |
| Breakdown voltage | I _R = 1.0 mA | T _A = 25 °C | V_{BR} | 100 (minimum) | - | V |
| Instantaneous forward voltage | I _E = 4.0 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.68 | 0.77 | V |
| | IF = 4.0 A | T _A = 125 °C | | 0.61 | 0.69 | |
| Reverse current | V _R = 70 V | T _A = 25 °C | I _R ⁽²⁾ | 1.5 | - | μA |
| | v _R = 70 v | T _A = 125 °C | | 1.2 | - | mA |
| | V _R = 100 V | T _A = 25 °C | | 7.0 | 250 | μA |
| | V _R = 100 V | T _A = 125 °C | | 3.6 | 20 | mA |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 230 | - | pF |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | |
|---|---------------------------------|----------|------|--|
| PARAMETER | SYMBOL | VSSB410S | UNIT | |
| Typical thermal resistance | R _{θJA} ⁽¹⁾ | 120 | °C/W | |
| | R _{0JM} (2) | 15 | | |

Notes

 $^{(1)}$ Free air, mounted on recommended P.C.B. 1 oz. pad area. Thermal resistance $R_{\theta JA}$ - junction to ambient

 $^{(2)}$ Units mounted on P.C.B. with 14 mm x 14 mm copper pad areas. $R_{\theta JM}$ - junction to mount

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| VSSB410S-M3/52T | 0.096 | 52T | 750 | 7" diameter plastic tape and reel | |
| VSSB410S-M3/5BT | 0.096 | 5BT | 3200 | 13" diameter plastic tape and reel | |

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

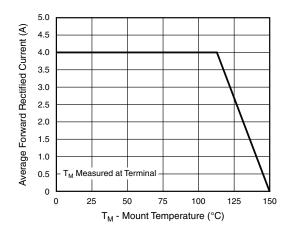


Fig. 1 - Maximum Forward Current Derating Curve

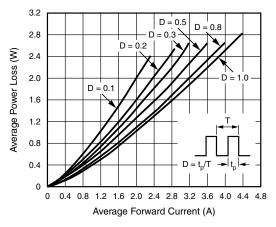


Fig. 2 - Forward Power Loss Characteristics

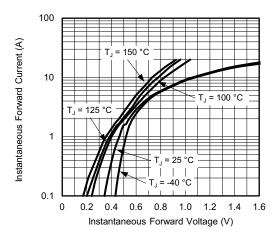


Fig. 3 - Typical Instantaneous Forward Characteristics

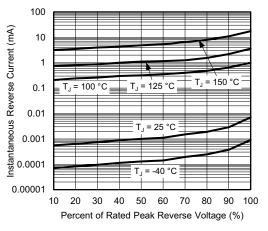


Fig. 4 - Typical Reverse Characteristics

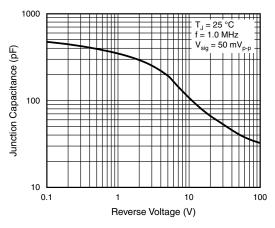


Fig. 5 - Typical Junction Capacitance

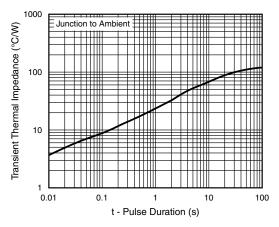


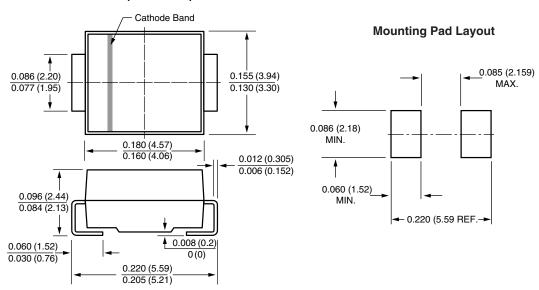
Fig. 6 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMB (DO-214AA)





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